Analog Power AM2302NE

N-Channel 20-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

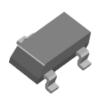
•	Low $r_{DS(on)}$ provides higher efficiency and
	extends battery life

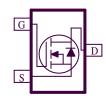
- Low thermal impedance copper leadframe SOT-23 saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY				
V _{DS} (V)	$r_{DS(on)}(\Omega)$	$I_{D}(A)$		
20	$0.076 @ V_{GS} = 4.5V$	3.4		
20	$0.103 @ V_{GS} = 2.5V$	2.9		



FREE





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ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)					
Parameter	Symbol	Maximum	Units		
Drain-Source Voltage			20	V	
Gate-Source Voltage			±8	V	
G .: D .: G .: a	T _A =25°C	т_	3.4		
Continuous Drain Current ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	ъ	2.2	A	
Pulsed Drain Current ^b	I_{DM}	10			
Continuous Source Current (Diode Conduction) ^a			1.6	A	
D a	T _A =25°C	D_	1.25	W	
Power Dissipation ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	Гр	0.8		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Maximum	Units		
Maximum Innation to Ambient ^a	$t \le 5 \sec$	R _{THJA}	100	°C/W	
Maximum Junction-to-Ambient ^a	Steady-State		166		

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

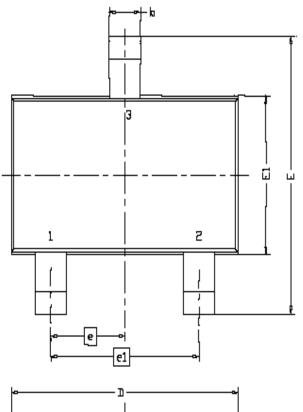
SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED)							
Dayamatan	Cb -1	T. 4 C. 12	Limits			T 124	
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \text{ uA}$	0.3			V	
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = 8 \text{ V}$			10	μΑ	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 16 \text{ V}, V_{GS} = 0 \text{ V}$			1	μА	
Zero Gate Voltage Drain Current	DSS	$V_{DS} = 16 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ} \text{C}$			10		
On-State Drain Current ^A	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	7			A	
Drain-Source On-Resistance ^A		$V_{GS} = 4.5 \text{ V}, I_D = 1 \text{ A}$			0.076	→ Ω	
Drain-Source On-Resistance	r _{DS(on)}	$V_{GS} = 2.5 \text{ V}, I_D = 1 \text{ A}$			0.103		
Forward Tranconductance ^A	$g_{ m fs}$	$V_{DS} = 5 \text{ V}, I_{D} = 1 \text{ A}$		7		S	
Diode Forward Voltage	V_{SD}	$I_S = 1 A, V_{GS} = 0 V$		0.7		V	
Dynamic ^b							
Total Gate Charge	Q_{g}	V - 10 V V - 4 5 V		1.9			
Gate-Source Charge	Q_{gs}	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V},$ $I_{D} = 1 \text{ A}$		0.4		nC	
Gate-Drain Charge	Q_{gd}	$I_D - I$ A		0.6			
Turn-On Delay Time	t _{d(on)}			7			
Rise Time	t _r	$V_{DD}=10$ V, $R_{L}=6~\Omega$, $R_{G}=6~\Omega,$		10		ns	
Turn-Off Delay Time	$t_{d(off)}$	$V_{GEN} = 4.5 \text{ V}$		20		1115	
Fall-Time	$t_{ m f}$			10			

Notes

- a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.
- b. Guaranteed by design, not subject to production testing.

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Package Information



DIM.	MILLIMETERS			
יהודת	MIN	NDM	MAX	
Α	0.935	0.95	1.10	
A1	0.01		0.10	
A2	0.85	0.90	0.925	
Ь	0.30	0.40	0.50	
С	0.10	0.15	0,25	
D	2.70	2.90	3.10	
Ε	2.60	2.80	3.00	
E1	1.40	1.60	1.80	
6	0.95 BSC			
el	1.90 BSC			
L	0.30	0.40	0.60	
L1	0.60REF			
L2	0,25BSC			
R	0.10			
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81	7 " N□M			

